

## T498D226M016ZTE800

Obsolete

B45196P, Tantalum, MnO<sub>2</sub> Tantalum, High Temperature, 22 uF, 20%, 16 VDC, SMD, Molded, High Temperature, N/A, 800 mOhms, 7343, Height Max = 3.1mm



General Information	
Series	B45196P
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Notes	Obsolete.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
K	1.8mm TYP

Specifications	
Capacitance	22 uF
Capacitance Tolerance	20%
Voltage DC	16 VDC (85C), 12.75 VDC (125C), 10.72 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	0.8 Ohms (100kHz)
Ripple Current	433 mAmps (25C), 389.7 mAmps (85C), 173.2 mAmps (125C)
Leakage Current	3.6 uA

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	750

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